Model No.	E1-4036AUR1-CT
Rev.	А

PRODUCT SPECIFICATION

Model No.: E1-4036AUR1-CT

Descriptions & Features:

- ■LED Numeric Display
- ■Case mold type.
- ■RoHS compliant.
- ■Low current operation
- ■Low power consumption.
- ■Easy mounting on P.C. board or socket.





CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY	

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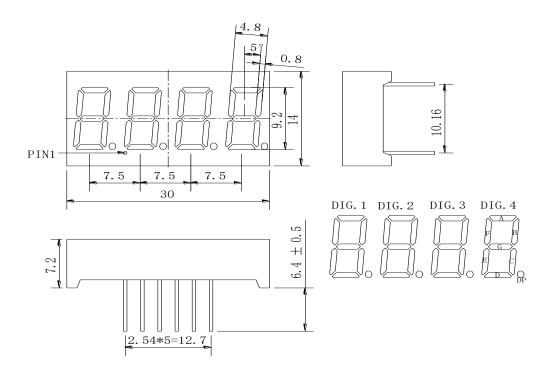
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■ -XX: REF Surface / Epoxy color

Color Number	0	1	2	3	4
REF Surface Color	○ White	O Black	● Gray	○ Red	○ Green
Epoxy Color	O Water Clear	White	○ Red	O Green	○ Yellow

■ Mechanical Dimensions



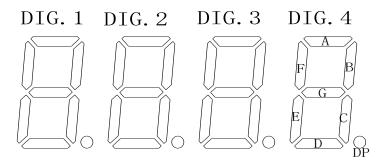
Notes:

- 1. All pins are Φ0.51[.018]mm
- 2. Dimension in millimeter [inch], tolerance is ±0.25 [.010] and angle is ±1° unless otherwise noted.
- 3. Bending≤Length*1%.
- 4. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

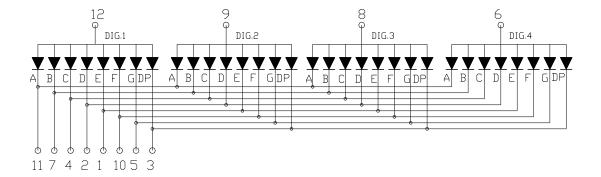
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■ All Light On Segments Feature & Pin Position



■ Internal Circuit Diagrams



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■ Absolute maximum ratings

(Ta=25°C)

Parameter	Symbol	Test Condition	Value		Unit
i didilietei	Symbol Test Condition		Min	Max	Offic
Reverse Voltage	VR	IR=30	5	_	V
Forward Current	IF	_	_	30	mA
Power Dissipation	Pd	_	_	100	mW
Pulse Current	Ipeak	Duty=0.1mS,1KHz	_	150	mA
Operating Temperature	Topr	_	-40	+85	${\mathbb C}$
Storage Temperature	Tstr	_	-40	+85	${\mathbb C}$

■ Electrical-Optical Characteristics

• Color Code & Chip Characteristics:(Test Condition:IF=20mA)

(Ta=25°C)

Emitting Color		Dice Peak Wave Material Length(λ _P)		Spectral Line halfwidth(Δ	Forward Voltage(VF) Unit:V		Luminous Intensity (Iv)		
				λ1/2)	Тур	Max	Unit:mcd		
Standard brightness									
PR	Red	GaP	700nm	90nm	2.00	2.50	0.5~1		
HR	Hi Red	AlGaAs	650nm	20nm	1.80	2.50	10~15		
SR	Super Red	AlGaAs	640nm	20nm	1.90	2.50	20~30		
HE	Orange	GaAsP	625nm	35nm	2.00	2.50	10~15		
НО	Amber	GaAsP	610nm	35nm	2.00	2.50	10~15		
HY	Yellow	GaAsP	590nm	35nm	2.00	2.50	10~15		
HG	Green	GaP	570nm	10nm	2.20	2.50	10~15		
			430nm		3.40	4.40	4~8(mw)		
SB	Blue	InGaN	460nm	60nm	3.20	3.80	6~12(mw)		
			470nm		3.20	3.80	6~12(mw)		
	Pure Green	InGaN	520nm	36nm	3.00	3.80	6~12(mw)		
SW	White	InGaN	X=0.29,Y=0.30	CCT:9500K	3.20	3.80	60~120		
	brightness								
UR	Ultra Red	AlGaInP	635nm	20nm	1.90	2.50	30~60		
UE	Ultra Orange	AlGalnP	625nm	20nm	1.80	2.30	60~120		
UO	Ultra Amber	AlGaInP	610nm	20nm	1.90	2.50	60~120		
UY	Ultra Yellow	AlGalnP	590nm	20nm	1.90	2.50	60~120		
UG	Ultra Green	AlGaInP	570nm	30nm	1.80	2.30	30~60		
PG	Ultra Pure Green	InGaN	520nm	36nm	3.00	3.80	180~300		
BG	Ultra Bluish Green	InGaN	505nm	36nm	3.00	3.80	180~300		
UB	UB Ultra Blue	InGaN	460nm	30nm	3.20	3.80	60~120		
			470nm	30nm	3.20	3.80	60~120		
UW	Ultra White	InGaN	X=0.29,Y=0.30	CCT:9500K	3.20	3.80	120~200		
Segment-to-Segment Luminous Intensity ratio(Iv-M) 1.5:1									

Note:

1.Luminous Intensity is based on the Long Da standards.

2.Pay attention about static for InGaN

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